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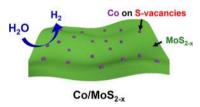
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Enhancing Catalytic Activity of MoS₂ Basal Plane S-Vacancy by Co Cluster Addition

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ABSTRACT: The basal plane of molybdenum disulfide (MoS_2) was recently activated for hydrogen evolution reaction (HER) by creating sulfur (S) vacancies (MoS_{2-x}) . However, the HER activity of those S-vacancies depends on the concentration of S-vacancies, imposing a dilemma for either improving activity per site or increasing overall active site density. Herein, we use density functional theory (DFT) calculations and experiments to show that the HER activities of MoS_{2-x} are greatly enhanced by adding cobalt (Co) clusters on the basal plane. Our DFT results show that the highest HER activity is achieved when the Co clusters are anchored on the S-vacancies with the interface of Co–Mo as the preferred active site. Our

Co enhances MoS_{2-x} HER activity



experiments confirm that the addition of Co enhances the activity per unit active site and increases the electrochemical active surface area. These results demonstrate the basal plane activity of MoS_{2-x} can be enhanced by decorating S-vacancies with transition-metal clusters.

Developing efficient electrocatalysts for hydrogen evolution reaction (HER) has been widely pursued because of its importance in electrolysis to produce

hydrogen (H_2) .¹ Molybdenum disulfide (MoS_2) has risen up as a promising alternative to the state-of-the-art electrocatalyst Pt because of its abundance and great activity, selectivity, and stability for HER.²-6 Previously, only the edge sites of MoS_2 were active for HER,²-7,8 with a hydrogen adsorption free energy (ΔG_H) of about 0.06 eV,³ and extensive research has been dedicated to maximizing the exposed edge site density. Recently, the basal plane of MoS_2 and molybdenum diselenide $(MoSe_2)$ was successfully activated for HER by generating sulfur (S) and selenium (Se) vacancies, respectively. Separating sulfur (S) and selenium (Se) vacancies, respectively. Separating sulfur (Se) and selenium (Se) vacancies generated by diverse methods, such as argon plasma treatment, hydrogen annealing, and electrochemical desulfurization, were all shown to be active toward HER, demonstrating the great promise of using the basal plane of MoS_2 for HER.

Nevertheless, the calculated $\Delta G_{\rm H}$ value for the S-vacancy over monolayer 2H phase MoS₂ changes from 0.2 eV to -0.2 eV when the S-vacancy concentration increases from 3% to 25% (%S-vacancy is defined as the number of S-vacancies over the total number of possible S atoms). This result implies critical limitations in using the basal plane of MoS₂, especially

multilayer MoS₂, for HER. First, the basal plane S-vacancy concentration needs to be precisely controlled to achieve its optimal ΔG_{H} . Such precise control of S-vacancy concentration is challenging to realize for multilayer MoS2 experimentally. Second, the optimal concentration of S-vacancy is not established for multilayer MoS2, and its dependence on the number of layers is unclear. The interlayer distance of the MoS_2 is >3.5 Å, implying the catalytic activity of lowconcentration S-vacancy at the surface of MoS2 is likely independent of interlayer interactions. However, as the Svacancy concentration increases, it becomes prudent to consider structural deformation of the top layer along with interlayer S-vacancy diffusion (Figure S1). Because of the complexity of the given system and high computational cost of working with big supercells of MoS₂, a comprehensive picture of the interlayer interactions and the dependence of the catalytic activity on the S-vacancy concentration for multilayer MoS₂ remains elusive. Third, the existence of the optimal Svacancy concentration imposes an upper limit for the active

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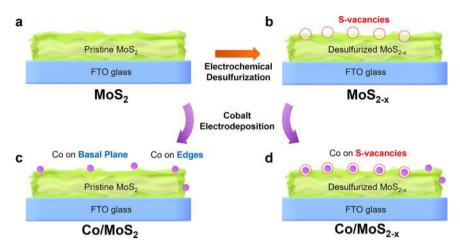


Figure 1. Schematic of the synthesis procedures. The overall synthesis steps of Co/MoS_{2-x} (MoS_2 with basal plane S-vacancy) and its control sample of Co/MoS_2 (pristine MoS_2) are schematically illustrated. (a) Pristine MoS_2 multilayers are grown on a supporting substrate (e.g., FTO glass). (b) S-vacancies are generated by electrochemical desulfurization, leading to desulfurized MoS_{2-x} . Finally, Co is electrodeposited on top of MoS_2 and MoS_{2-x} to form Co/MoS_2 (c) and Co/MoS_{2-x} (d), respectively. The detailed synthesis steps are described in the Supporting Information.

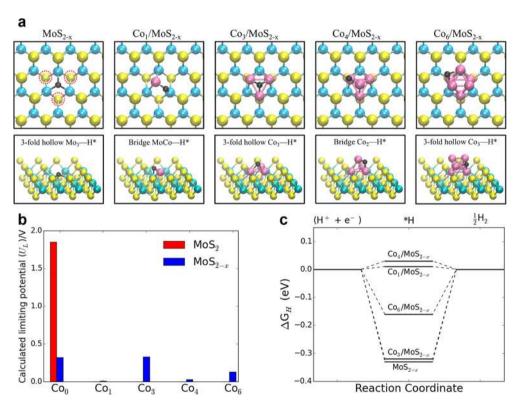


Figure 2. DFT-calculated HER activity over Co_n/MoS_{2-x} . (a) Top and side views for the optimized hydrogen adsorption on desulfurized MoS_{2-x} in the absence and presence of Co clusters. Three S-vacancies are marked with dashed red circles in MoS_{2-x} . Color code: Mo, cyan; Co, purple; S, yellow; H, black. (b) Calculated limiting potential for MoS_{2-x} in the absence (Co_0) and presence of cobalt clusters $(Co_1, Co_3, Co_4, and Co_6)$. (c) Free-energy diagram for Co_n clusters embedded in MoS_{2-x} .

site density on the basal plane of MoS_2 . It is therefore of great interest to weaken the interdependence between the ΔG_H value of the individual S-vacancy and the concentration of S-vacancy. In practice, for a given concentration of the basal plane S-vacancy for MoS_2 , we need to identify new ways to improve its activity for HER to fully utilize the potential of basal planes of MoS_2 .

Cobalt (Co), as a nonprecious metal, is known to promote catalytic activity of the edge sites of MoS_2 . In the presence of Co atoms, MoS_2 exhibits enhanced activity for not only

HER^{19–21} but also water gas shift^{22,23} and oxygen reduction reactions.²⁴ Recently, single-site atomic Co was successfully doped in the basal plane S-vacancies of MoS₂, leading to a significant improvement in catalytic activity for the hydrodeoxygenation (HDO) reaction.²⁵

Herein, by combining theory and experiment, we demonstrate that adding Co atoms over the basal plane of desulfurized MoS_{2-x} (Figure 1) substantially enhances the HER activity. According to our DFT calculations, the Co atoms directly connected to the MoS_{2-x} basal plane are the

preferred adsorption sites for hydrogen. The significant enhancement is observed when Co atoms are anchored in the S-vacancies with the interface of Co-Mo as the preferred active site, which is further supported by the XAS experiments. For Co/MoS₂ studied as a control sample (Figure 1c), the Co addition, mainly occurring at edge sites, does not change the electrochemical active surface area (ECSA) but enhances the activity per unit site. In contrast, for Co/MoS_{2-x} (Figure 1d), the Co addition increases both the activity per active site and ECSA. For the desulfurized MoS_{2-x} multilayers supported on carbon foams, the deposition of Co reduces the overpotential at -10 mA/cm² from -0.32 to -0.21 V vs RHE for Co/ MoS_{2-x}, which is comparable to the state-of-the-art MoS₂based catalysts (-0.25 to -0.11 V vs RHE). These results demonstrate the effectiveness and potential of modifying the intrinsic basal plane S-vacancy activity with transition metals, which could be applied to other catalytic reactions.

Theoretical Analysis. According to previously reported DFT analysis, single S-vacancies in MoS_2 significantly promote the HER activity. However, the separated small S-vacancies are not thermodynamically stable and tend to agglomerate and form larger S-vacancies. A too high concentration of S-vacancies leads to a too strong interaction of HER intermediate (H*) with the MoS_2 basal plane, lowering the HER activity as reported previously. ¹⁶

Our strategy to maintain the high HER activity of the S-vacancies in the basal plane is to embed Co clusters in the S-vacancies. We calculate the hydrogen adsorption free energy $(\Delta G_{\rm H}^0*)$ over a monolayer series of desulfurized ${\rm MoS}_{2-x}$ (Figure 2a) with different Co clusters (${\rm Co}_n$ with n=0,1,3,4, and 6) and find the limiting potential ($U_{\rm L}=|\Delta G_{\rm H}^0*|/e)$ (see Computational Details in the Supporting Information) to estimate the activity. The equilibrium potential for HER is 0.0 V, and a lower calculated $U_{\rm L}$ represents a higher activity.

Figure 2b compares the $U_{\rm L}$ for the various structures in Figure 2a, and Figure 2c displays the free energy diagram for HER over MoS_{2-x} in the presence and absence of embedded Co_n clusters. According to our DFT calculations, the pristine MoS_2 binds H* very weakly, resulting in a U_L of ~ 1.90 V, in agreement with the previous report. 16 Removal of a single S atom from the pristine MoS_2 (S-vacancy percentage $\approx 3.1\%$) strengthens the interaction of H* with the remaining framework with $U_{\rm L} \approx 0.10$ V, indicating a considerable improvement in HER activity. It is worth noting that the single S-vacancies thermodynamically favor aggregating to form larger S-vacancies that tend to adsorb H* strongly and hence poison the catalyst. For example, removal of three sulfur atoms from the MoS₂ slab results in a triangle-shaped vacancy (Figure 2a, left; S-vacancy percentage \approx 9.4%). Such a vacancy exposes three Mo atoms, which favorably adsorb H* leading to $U_{\rm L} \approx$ 0.33 V (Figure 2b, Co₀, blue bar). Expanding the triangleshaped S-vacancy by removal of the next three nearest sulfur atoms (Figure S2, S-vacancy percentage ≈ 18.8%) results in a stronger hydrogen adsorption free energy with $U_{\rm L} \approx 0.54$ V. We next consider the presence of Co atoms on the HER activity of the MoS₂.

A previous study by Liu et al. showed that the addition of Co complexes to a solution of MoS_2 leads to the accommodation of single Co atoms on the basal plane of MoS_2 . A single Co atom can chemisorb on one of the two chemically nonequivalent S_3 sites at the surface of MoS_2 , namely hollow and Mo atop sites (Figure S3A and S3B). These single Co atoms prefer to migrate and fill a nearby single

S-vacancy that may form because of elevated temperature (S atop site, Figure S3C). Of note, the later configuration is equivalent to one generated by substitution of a sulfur atom with a single Co. Our DFT results show a chemisorbed Co atom on the hollow, Mo atop, or S atop sites adsorbs H* with $\Delta G_{\rm H*}^0 = 0.67$, 0.40, and 0.64 eV, respectively. This indicates that these sites would present considerable overpotentials for HER. We next investigate HER activity of an embedded Co on a larger S-vacancy.

The substitution of a sulfur atom by Co can promote the generation of proximal S-vacancy in an exothermic manner.²⁵ Therefore, we consider removal of two sulfur atoms in the vicinity of an embedded Co and evaluate HER activity. Of note, there are two possible configurations for the removal of two sulfur atoms near the Co, i.e., $Co_1/MoS_{2-x(a)}$ and $Co_1/MoS_{2-x(a)}$ $MoS_{2-x(b)}$, Figure S4. These configurations adsorb H* favorably with $U_{\rm L} \approx 0.25$ and 0.13 V, respectively. It is worth noting that the embedded Co atom may migrate to bond with three Mo atoms around the hollow site with $U_{\rm L} \approx$ 0.01 V ($Co_1/MoS_{2-x(c)}$, Figure S4). The calculated formation energies are almost similar (within $\sim 0.1 \text{ eV}$) for all these three configurations of Co₁/MoS_{2-x}. The H* is preferentially adsorbed at the interface of Co-Mo for Co₁/MoS_{2-x(a)} (Figure S5) and $Co_1/MoS_{2-x(c)}$ (Figure 2a, second left), while for Co₁/MoS_{2-x(b)} the cavity composed of three Mo and the Co is the active site (Figure S5). In addition to single Co atoms, we also examined the activity of other Co_n clusters (n =3, 4, 6) embedded in the vacancies of MoS_{2-x} . For $Co_n/$ MoS_{2-x} systems, several configurations are examined via DFT optimization, and the most stable ones are reported here. As shown in Figure 2b, the calculated U_L values over Co_3/MoS_{2-x} Co₄/MoS_{2-x}, and Co₆/MoS_{2-x} structures are 0.33, 0.03, and 0.13 V, respectively, which are lower than that of MoS_{2-x} and MoS₂. Therefore, the HER activity decreases in the order of $Co_n/MoS_{2-x} > MoS_{2-x} > MoS_2$. The preferred adsorption site for H* over Co_3/MoS_{2-x} and Co_6/MoS_{2-x} is the 3-fold hollow site (Figure 2a). Among several possible 3-fold hollow sites in the supported Co₆, those with cobalt atoms directly connected to the supports are favored. For the Co_4/MoS_{2-x} the Co-Cobridge site is the preferred active site, where one of the Co atoms involved in the adsorption is directly connected to the MoS₂ substrate (Figure 2a).

The theoretical results presented above reveal desirable synergic effects between additional Co atoms and MoS₂ support and offer a potentially interesting system for achieving significantly high HER activity. The most salient aspect of our DFT results is that the HER activity can be drastically improved in the presence of embedded Co atoms in the Svacancies with the interface of Co-Mo being the most active motif. While our DFT study reported here contributes novel insights on the promotional effect of Co atoms on HER activity of MoS2, some aspects are not properly accounted for in our analysis because of high computational expenses. These include the influence of Co clusters and S-vacancy size on the HER activity. Therefore, it would be worthwhile in the future to extend the current DFT study to bigger metal clusters embedded on a wide range of S-vacancies and their effect on HER catalytic activity.

Synthesis of Co/MoS_2 and Co/MoS_{2-x} . To support our theoretical results, we experimentally investigate the HER activity of the basal plane S-vacancy for MoS_2 (i.e., desulfurized MoS_{2-x}) multilayers in the presence of electrodeposited Co atoms. We synthesized polycrystalline 2H phase MoS_2

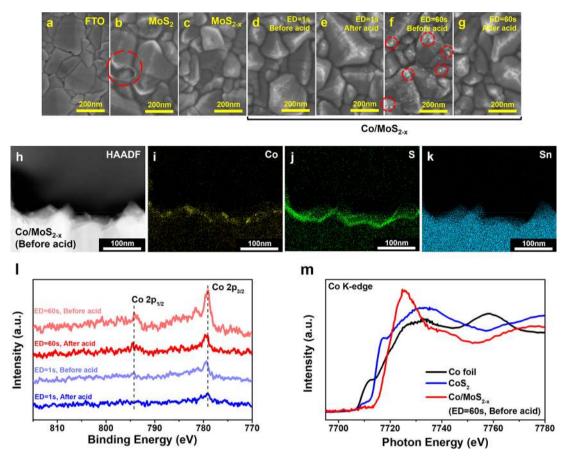


Figure 3. Materials characterization of Co/MoS_{2-x} film on FTO substrate. (a-g) SEM images of FTO, MoS_2 , MoS_{2-x} , Co/MoS_{2-x} (ED = 1 s, before and after acid etching), and Co/MoS_{2-x} (ED = 60 s, before and after acid etching). ED refers to electrodeposition time of Co. (h-k) STEM image of Co/MoS_{2-x} (ED = 60 s, before acid etching) (h) and corresponding EDS elemental mappings of Co, S, and Sn, respectively (i-k). (l) XPS spectrum of Co 2p region of Co/MoS_{2-x} (ED = 1 s and 60 s) before and after acid etching. (m) Co K-edge XANES spectra of Co metal foil, CoS_2 and Co/MoS_{2-x} (ED = 60 s, before acid etching).

multilayers supported on FTO glasses (Figure 1a) or carbon foams through thermolysis. S-vacancies were generated on the basal plane of MoS_2 using the electrochemical desulfurization method that we developed previously (Figure 1b). Co was electrodeposited onto both pristine MoS_2 (Co/MoS_2) and desulfurized MoS_{2-x} (Co/MoS_{2-x}) for comparison purposes. Because the basal plane S-vacancy is coordinatively unsaturated like edge sites, the deposited Co atoms are expected to be incorporated mainly at the edge sites for Co/MoS_2 (Figure 1c) but on both the basal planes and the edge sites for Co/MoS_{2-x} (Figure 1d).

Morphology and Composition Characterization of Co/MoS_{2-x} on FTO. Panels a-g of Figure 3 show the scanning electron microscopy (SEM) images of bare FTO, pristine MoS₂, desulfurized MoS_{2-x} , Co/MoS_{2-x} (ED = 1 s, before and after acid etching), and Co/MoS_{2-x} (ED = 60 s, before and after acid etching). After synthesis of pristine MoS₂, the transparent FTO becomes dark brownish. Although the grain of FTO remains clear, small holes in MoS2 can be observed in Figure 3b (red dotted circle). The composition of 2H phase MoS₂ multilayers is further confirmed by both Raman spectra (Figure S6a) and X-ray photoelectron spectroscopy (XPS) measurement (Figure S6b,c). After desulfurization, no significant morphology or color change can be observed between pristine MoS₂ (Figure 3b) and desulfurized MoS_{2-x} (Figure 3c). After 1 s of ED Co, the SEM image does not show any visible morphology change (Figure 3d) and the XPS spectrum shows

a small Co $2p_{3/2}$ peak at 779.1 eV (Figure 31). Other than XPS, it is difficult to characterize the existence of Co because of its small amount. To further confirm the deposition of Co, we also inspected the Co/MoS_{2-x} sample with a much longer ED time of 60 s, which clearly shows the small particle formation on top (Figure 3f, red dotted circles). In addition, the Co/ MoS_{2-x} (ED = 60 s) clearly shows two main Co 2p peaks of Co $2p_{3/2}$ at 779.1 eV and another Co $2p_{1/2}$ at 794.5 eV (Figure 31). The cross-sectional scanning transmission electron microscopy-high-angle annular dark field (STEM-HAADF) image of Co/MoS_{2-x} (ED = 60 s) shows that the thickness of MoS₂ multilayer is around 10 nm (Figure 3h). The thickness is also confirmed by the EDS elemental maps of S and Sn element (Figure 3j,k). The Co mapping from the above Co–K peak (~6.9 keV) shows that Co exists in small particles with size from a few nanometers to ~ 10 nm in the Co/MoS_{2-x} (ED = 60 s) sample (Figure 3i). Similar elemental distributions are observed by TEM and STEM-HAADF images and EDS elemental mappings of other areas (Figures S7 and S8). HRTEM images show that the Co particles (ED = 60 s) are CoO nanoparticles (Figure S9).

Those characterizations confirm the deposition of Co onto MoS_{2-x} . However, our HER measurement is carried out in strong acidic conditions, where CoO is not stable. To test if some Co will remain during the HER, we soaked Co/MoS_{2-x} of both ED = 1 s and ED = 60 s in 0.5 M H_2SO_4 for around 1 min and compared the SEM and XPS afterward. For the Co/

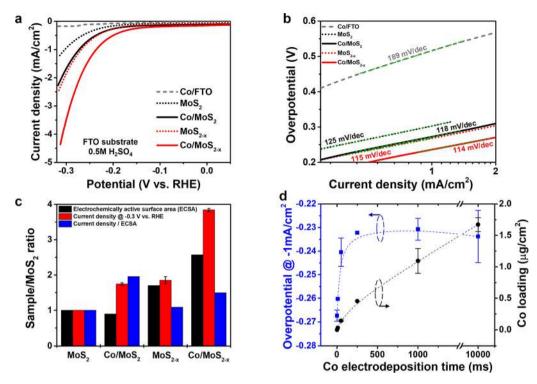


Figure 4. HER catalytic activity of Co, MoS_{2-x} , MoS_{2-x} , Mo

 MoS_{2-x} (ED = 1 s) sample, both the SEM image (Figure 3e) and XPS spectrum (Figure 31) show little difference, and the Co $2p_{3/2}$ peak remains. For the Co/MoS_{2-x} (ED = 60 s) sample, after the acid etching step, the surface particles are gone (Figure 3g) and the two Co 2p peaks become weaker. This shows that the CoO particles are not stable during the acidic testing conditions of HER. Nevertheless, for both samples after acid etching, the remaining Co 2p XPS spectra are similar to those of atomic cobalt doped on MoS_{2-x}^{25} and Co ion promoted amorphous MoS_3^{19} It is challenging for direct TEM observation of the Co-Mo bond for Co/MoS_{2-x} on FTO (after acid etching) because of the small concentration of the Co atoms, the multilayer nature of the MoS₂ ,and the rough surface of FTO glass. To better understand the adsorption configuration of Co doping in MoS_{2-x} (before etching), we performed Co K-edge XAS experiments. The Co K-edge XAS results (Figure 3m) show that the spectral shape of $Co/MoS_{2-x}/FTO$ (ED = 60 s, before acid etching) is largely different from Co metal foil and CoS₂, which suggests the absence of Co-S bonds. This suggests that Co atoms are mainly presented in the forms of CoO²⁷ and Co-Mo before the etching process. Because acid etching removed CoO, the Co atom is in the form of Co-Mo in Co/ MoS_{2-x} on FTO (after acid etching), which is consistent with our DFT calculation configurations (Figure 2). The existence of the Co-Mo bond is more evident for samples supported on carbon foams (Figure 5d-g) because of larger X-ray absorption near-edge structure (XANES) and extended X-ray absorption fine structure (EXAFS) signals.

HER Activity of Co/MoS_{2-x} on FTO. Figure 4a shows the polarization curves of pristine MoS_2 , desulfurized MoS_{2-x} , Co/MoS_2 , Co/MoS_{2-x} (ED = 1 s), and Co directly deposited on

FTO measured in 0.5 M H₂SO₄ electrolyte. These polarization curves were measured through linear sweep voltammetry with a scan rate of 10 mV/s, and they were iR-corrected. The current density values are calculated based on the projected area of the FTO substrate. The current density increases in the order of Co/FTO < MoS_2 < $MoS_{2-x} \approx Co/MoS_2$ < Co/MoS_{2-x}. The corresponding Tafel plots are shown in Figure 4b. The extracted Tafel slopes decrease as follows: Co/FTO of 189 mV/dec, MoS_2 of 125 mV/dec, MoS_{2-x} of 118 mV/dec, Co/MoS_2 of 115 mV/dec, and Co/MoS_{2-x} of 114 mV/dec. Though the Tafel slope of Co/MoS_{2-x} is slightly greater than that of Co/MoS₂, its exchange current density (9.206 \times 10⁻⁶ A/cm²) listed in Table S1 is about twice that of Co/MoS₂ $(5.205 \times 10^{-6} \text{ A/cm}^2)$, indicating the superior intrinsic catalytic activity of Co/MoS_{2-x} over Co/MoS₂. These results show that the HER activity of MoS₂ is increased after desulfurization, which is consistent with previous studies. 16 Notably, the HER activities of both MoS₂ and MoS_{2-r} are improved after Co electrodeposition and the HER activity of Co/MoS_{2-x} is higher than that of Co/MoS_2 . It should be noted that when Co is directly deposited on FTO (Figure 4a, Co/FTO), it shows negligible activity for HER. These results are in an agreement with our DFT calculation that the HER activity is enhanced because of the synergy effect between Co atoms and the basal plane vacancies of MoS2 support (Figure 2c).

We further measured the electrochemically active surface area (ECSA) using cyclic voltamograms (Figure S10) to further identify the origin of the higher HER activity of Co/ MoS_{2-x} over other samples. Figure 4c displays the normalized ECSA (black bars), current density at -0.3 V vs RHE (red bars), and current density per ECSA (blue bars) for several

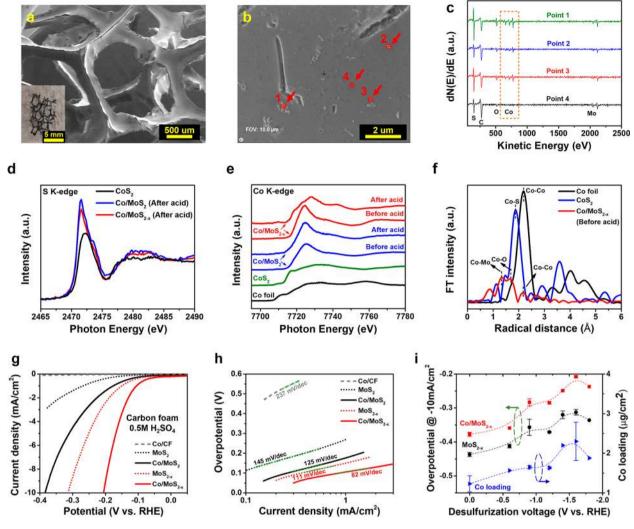


Figure 5. Material and HER catalytic activity characterization of Co/MoS_{2-x} film supported on carbon foams. (a and b) SEM images of low-and high-resolution for Co/MoS_{2-x} (ED = 60 s, before acid etching) on carbon foam. The inset in panel a shows an optical image. (c) Differentiated AES spectra of the four different points marked in panel b. Points 1–3 show signals of Co. (d) S K-edge XANES spectra of CoS_2 , Co/MoS_2 , and Co/MoS_{2-x} (ED = 60 s, after acid etching). (e) Co K-edge XANES spectra of Co metal foil, CoS_2 , Co/MoS_2 , and Co/MoS_{2-x} (ED = 60 s, before acid etching). (g) Polarization curves of Co, MoS_2 , MoS_2 , Mo

samples, which are normalized by the pristine MoS₂ sample for comparison. The change in current density value reflects the combined change of ECSA (Figure 4c, black bars) and the intrinsic activity of each site. The ECSAs in Co/MoS2 and MoS₂ are very similar. Therefore, the current density enhancement in Co/MoS₂ comes from the increase of intrinsic activity per active site. This is reasonable as Co is known to increase the intrinsic activity of S edge sites. ^{21,29} When MoS_{2-x} is compared with MoS2, the ECSA shows an apparent increase (1.7 times), which confirms newly created active sites of Svacancies in the basal plane. The increase of current density is similar to that of ECSA here between MoS_{2-x} and MoS₂, which shows that the basal plane S-vacancy has comparable activity with the S edge sites. Finally, the ECSA of Co/MoS_{2-x} is even higher than MoS_{2-x} indicating that Co addition leads to more active sites on the basal planes. The possible explanation is that some S-vacancies for MoS2-x are not in the optimal concentration range locally, so they do not contribute much

to HER. After Co deposition, their HER activities are higher and become effective active sites. In addition, the enhanced intrinsic HER activity per site of Co/MoS_{2-x} was estimated by dividing the normalized current density with the ECSA (Figure 4c, blue bar > 1), confirming our DFT calculation (Figure 2) in that the intrinsic active site density of S-vacancy is also improved with Co deposition.

We further tested the effect of Co deposition amount in Co/ MoS_{2-x} on HER activity. The Co amount (Figure 4d, black circles) is changed by varying the electrodeposition time from 0 to 10 s. Figure 4d shows the HER overpotential (defined as the potential to achieve $-1~mA/cm^2$) as a function of the Co electrodeposition time. The Co amount is estimated by integrating the deposition current—time curve with the assumption of all charges going to form Co (Figure S11b). The Co amount in Co/ MoS_{2-x} increases linearly with increasing the deposition time (Figure 4d). However, the overpotential decreases initially with increasing the deposition

time but saturates at around -0.23 V vs RHE after 250 ms of Co electrodeposition (Figure 4d). Considering the SEM and XPS results in Figure 3, a possible explanation is that the initial deposited Co atoms form chemical bonds with Mo atoms. As more Co atoms are deposited, they grow into CoO nanoparticles, as we observed from HRTEM of Co/MoS_{2-x} (ED = 60 s, Figure 3i). Those CoO nanoparticles are dissolved during the HER test in acidic conditions. Co atoms that form chemical bonds with Mo atoms in the vacancy contribute to the HER activity. Finally, we did not vary the amount of Co deposition by varying the desulfurization voltage to change the S-vacancy concentration for MoS_{2-x} on FTO because the higher desulfurization voltage deteriorates the adhesion between MoS₂ and FTO electrode. Such control study was carried out on carbon foams, as discussed in Figure 5f, because carbon foams have much better adhesion with MoS2 than FTO.16

HER Activity of Co/MoS_{2-x} on Carbon Foams. We further test if our Co deposition method will enhance MoS_{2-x} deposited on three-dimensional substrates of more practical relevance. We changed the underneath substrate from flat FTO to commercial carbon foams (ERG Materials and Aerospace Corporation). The 2H phase polycrystalline MoS₂ multilayers were synthesized with the same thermolysis method as described in the Supporting Information. The SEM images of Co/MoS_{2-x} (ED = 60 s) on the carbon foam are shown in Figure 5a, and the inset shows its optical image. The carbon foam has ~10 pores per inch, and the pore diameter is about 2~3 mm. The specific surface area of the carbon foam was determined by the Brunauer-Emmett-Teller (BET) method with xenon gas adsorption to be 132.32 cm²/g. The presence of Co is confirmed by inspecting four points in Figure 5b by SEM/Auger electron spectroscopy (SEM/AES), where points 1-3 are selected on top of deposited particles and point 4 is not. The differentiated AES spectra in Figure 5c indicate that Co exists at points 1-3 with the kinetic energy of 658, 718, and 777 eV for Co and that point 4 is mainly MoS_{2-x} without

To better understand the adsorption configuration of Svacancy and Co on Co/MoS_{2-x} on carbon foam, we performed S and Co K-edge XAS experiments. The S K-edge peak intensity of Co/MoS_{2-x} is weaker than that of Co/MoS_2 (Figure 5d), suggesting the formation of S-vacancy by the electrochemical desulfurization process.³⁰ The S K-edge at 2470 eV with the shoulder at 2473 eV indicates the Mo-S bond in MoS₂.³¹ In addition, the S K-edge XANES results show that the spectral shapes of Co/MoS₂ and Co/MoS_{2-x} are different from that of CoS₂, indicating the absence of Co-S bonds. The Co K-edge XANES results (Figure 5e) further show that both Co/MoS₂ and Co/MoS_{2-x} before and after acid etching have different features with CoS2 and Co metal foils. This suggests that Co atoms are mainly presented in the forms of Co-Mo and CoO before acid etching, consistent with the results for FTO substrates (Figure 3m). The Co XAS spectral shape changes significantly after acid etching with the main absorption edge shifting to lower energies (Figure 5e), which indicates that CoO is partially removed during the etching process. To further validate the results, we measured the Co K-edge EXAFS for Co/MoS_{2-x} before acid etching. Co K-edge EXAFS is utilized to acquire structural parameters such as coordination numbers and bond lengths around Co. Figure 5f shows the Fourier transformed (FT) curves of Co/MoS_{2-x} in comparison with the reference samples of CoS₂ and Co foil,

and the corresponding k^3 -weighted EXAFS $\chi(k)$ spectra are shown in Figure S12. The results show that no Co-S bonding configuration is observed; instead, the features at 1.8, 1.4, and 2.2 Å correspond to the Co-O, Co-Mo. and Co-Co^{32,33} bonds, respectively. Because CoO is removed by the acid etching process, the remaining Co atoms are mainly bonded with Mo in MoS_{2-x} with a lower oxidation state. In contrast, no apparent spectral shape change is observed for Co/MoS₂ before and after etching, suggesting that the bonding environment of Co atoms in MoS2 after etching is different from that of MoS_{2-x} after etching because of the presence of Svacancies on MoS_{2-x} . Finally, we have also conducted similar EXAFS measurements for Co/MoS_{2-x} on FTO, but the EXAFS signal is too weak to extract accurate information. The weak signal is due to the low loading amount of Co on a flat FTO substrate. The Co loading on porous carbon foam structure is much higher. Nevertheless, because we are preparing Co/MoS_{2-x} on FTO and carbon foam using the same method and both substrates are inert, we expect that the EXAFS results on carbon foam should be applicable to FTO substrate as well.

Figure 5g shows the polarization curves of pristine MoS₂, desulfurized MoS_{2-x} , Co/MoS_2 , Co/MoS_{2-x} (ED = 1 s), and Co directly deposited on carbon foam (CF) measured in 0.5 M H₂SO₄ electrolyte. Similar with the results on FTO substrates (Figure 4a,b), the current density increases in the order of Co/ $CF < MoS_2 < Co/MoS_2 < MoS_{2-x} < Co/MoS_{2-x}$ (Figure 5g). The corresponding Tafel slopes (Figure 5h) and the exchange current density (Table S1) follow the trend of HER activity improvement. The overpotential for Co/MoS_{2-x} on carbon foam is -0.21 V vs RHE (at 10 mA/cm^2), which is comparable to the state-of-the-art highly nanostructured MoS₂ catalyst (-0.25 to -0.11 V vs RHE). The stability of Co/MoS_{2-x} was tested using cyclic voltammograms for 1000 cycles between -0.3 and 0.2 V vs RHE at 100 mV/s. The *iR*-corrected initial and the final cathodic sweeps are shown in Figure S13. The overpotential at -10 mA/cm^2 decreased about 60 mV after the stability test. The instability is partially caused by hydrogen bubble generation, which exfoliates catalyst from the carbon foam. Another possible factor is the dissolution of a small amount of CoO nanoparticles. The stability is comparable to that of desulfurized MoS_{2-x} and better than that of amorphous cobalt sulfide (CoS_x) whose overpotential at -5 mA/cm² degrades about 250 mV after 500 potential sweeps.²⁰

Finally, we also tested the effect of Co loading on the HER activity of $Co/MoS_{2-x}/CF$ (ED = 1 s) by varying the desulfurization voltage. The desulfurization was carried out under each voltage for 3 min using chronoamperometry in 0.5 M H₂SO₄ electrolyte solution, the same as our previous work.¹⁶ Figure 5i plots the HER overpotential (left y-axis), defined as the potential to achieve -10 mA/cm^2 , for MoS_{2-x} (black) and Co/MoS_{2-x} (red) and the total Co loading (right y-axis) as a function of the desulfurization voltage. As the desulfurization voltage increases, higher concentration of Svacancy is generated, which leads to first reduced and then increased overpotential for MoS_{2-x} . This is consistent with previous DFT results in that there is an optimal range Svacancy for the HER activity. 13 Similarly, more S-vacancy provides more nucleation sites for Co, leading to higher loading of Co and lower overpotential for Co/MoS_{2-x} . These results show that the HER activity of MoS₂ can be improved by the combination of S-vacancy and Co deposition.

In summary, our combined DFT calculations and experiments have demonstrated that embedded Co atoms can significantly enhance the HER activity of both pristine MoS₂ and desulfurized MoS_{2-x} multilayers. According to our DFT calculations, there is a desirable synergy effect between the Co atoms directly connected to the S-vacancies, which provide a favorable site for hydrogen adsorption. Our experimental results show, for the control Co/MoS₂ sample, the Co atoms are mainly incorporated into the edge sites and their addition has little impact on ECSA but enhances the activity per unit site, as expected. In contrast, for Co/MoS_{2-x} , the Co atoms are incorporated into both basal planes and edge sites. Importantly, the embedded Co increases both ECSA and the activity per active site, suggesting an improvement of the activity of basal plane S-vacancies. For the desulfurized MoS_{2-x} multilayers supported on carbon foams, the deposition of Co reduces the overpotential at -10 mA/cm^2 from -0.32 to -0.21 V vs RHE for Co/MoS_{2-x}, which is comparable to the state-of-the-art MoS₂-based catalysts (-0.25 to -0.11 V vs RHE). The results of this work demonstrate the effect and potential of modifying the intrinsic basal plane S-vacancy activity with transition-metal atoms, which could be applied to other catalytic reactions as well.

ASSOCIATED CONTENT

S Supporting Information

The Supporting Information is available free of charge on the ACS Publications website at DOI: 10.1021/acsenergy-lett.8b01567.

Experimental and Computational Methods; DFT models; Raman spectra, XPS, TEM, HAADF-STEM, EDS, exchange current density, capacitive current, electrodeposition, EXAFS $\chi(k)$ spectra, and stability results (PDF)

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Author Contributions

VS.P., J.P., and H.A. contributed equally to this work. S.P., J.P., J.K.K., and X.Z. conceived the idea and designed the experiments. S.P. performed the material growth, electrode fabrication, material characterization, and electrochemical measurements. J.P. and J.Z. conducted the SEM, TEM, HAADF-STEM, and EDS characterizations. J.K.K. designed the schematic of the experimental process. S.S. conceived and designed the DFT calculations. H.A. performed the DFT calculations. L.Z. and J.G. conducted XAS experiments and analysis. S.P., J.P., X.Z., S.S., and H.A. wrote the manuscript, and all authors discussed the results and commented on the manuscript.

Notes

The authors declare no competing financial interest.

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